Quantum Dot Light-Emitting Diode with Ligand-Exchanged ZnCuInS₂ Quantum Dot

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SUMMARY Nowadays, semiconductor quantum dots have attracted intense attention as emissive materials for light-emitting diodes, due to their high photoluminescence quantum yield and the controllability of their photoluminescence spectrum by changing the core diameter. In general, semiconductor quantum dots contain large amounts of organic ligands around the core/shell structure to obtain dispersibility in solution, which leads to solution processability of the semiconductor quantum dot. Furthermore, organic ligands, such as straight alkyl chains, are generally insulating materials, which affects the carrier transport in thin-film light-emitting diodes. However, a detailed investigation has not been performed yet. In this paper, we investigated the luminance characteristics of quantum-dot light-emitting diodes containing ZnCuInS₂ quantum dots with different carbon chain lengths of alkyl thiol ligands as emitting layers. By evaluating the CH₂/CH₃ ratio from Fourier-transform infrared spectra and thermal analysis, it was found that approximately half of the oleylamine ligands were converted to alkyl thiol ligands, and the evaporation temperature increased with increasing carbon chain length of the alkyl thiol ligands based on thermogravimetric analysis. However, the photoluminescence quantum yield and the spectral shape were almost the same, even after the ligand-exchange process from the oleylamine ligand to the alkyl thiol ligand. The peak wavelength of the photoluminescence spectra and the photoluminescence quantum yield were approximately 610 nm and 10%, respectively, for all samples. In addition, the surface morphology of spin coated ZnCuInS₂ quantum-dot layers did not change after the ligand-exchange process, and the root-mean-square roughness was around 1 nm. Finally, the luminance efficiency of an inverted device structure increased with decreasing carbon chain length of the alkyl thiol ligands, which were connected around the ZnCuInS₂ quantum dots. The maximum luminance and current efficiency were 86 cd/m² and 0.083 cd/A, respectively.

key words: semiconductor quantum dot, quantum dot light-emitting diode, ligand exchange, alkyl thiol

1. Introduction

Organic light-emitting diodes (OLEDs) have been widely investigated for a long time, and flat-panel displays and general lighting employing OLEDs have already been implemented for practical use. By now, many kinds of organic emissive molecules, such as fluorescence, phosphorescence, and thermally activated delayed fluorescence materials, have been successfully synthesized for realizing high luminance efficiencies and long-term stability. On the other hand, semiconductor quantum dots (QDs) have also been used in emitting layers instead of the organic emissive molecules of OLEDs, and this type of device is known as a quantum-dot light-emitting diode (QLED) [1]. Semiconductor QDs have several advantages compared with organic molecules, such as long-term stability [2], the possibility of solution processing, and controlled photoluminescence (PL) spectra by changing the core diameter [3]. However, all-solution-processed devices [4], near-infrared emitters [5], and flexible device structures [6] have all been demonstrated with QLEDs.

In previous studies, Cd-based semiconductor QDs have been utilized as emissive materials for QLEDs due to their high PL quantum yield (PL-QY) and narrow PL spectra [7], [8]. However, Cd-based QDs are harmful to the environment and human health, and Cd-free semiconductor QDs have been strongly desired for a long time. InP [9], [10] and CuInS₂ [11], [12] QDs were found to exhibit high PL-QYs and luminance performance for the corresponding QLEDs by optimizing synthesis conditions, such as the synthesis temperature, the reaction time, the concentration of raw materials, and the insertion of a carrier blocking layer. Previous papers demonstrated that PL-QYs of more than 80% were achieved, and this value is high enough for practical display and biological applications [13], [14]. Furthermore, the luminance performance of QLEDs with Cd-free QDs has been improved by controlling the organic ligand [15]; however, further investigation is required due to insufficient understanding of carrier dynamics in QLEDs.

Zn-doping techniques for CuInS₂ and AgInS₂ QDs have been widely investigated due to their blue-shifted PL wavelength and high PL-QY [16], [17]. Since the PL wavelength is determined by the core diameter and the band gap energy of bulk materials, the Zn-doping-induced PL wavelength shift is useful for realizing a precise control of the PL wavelength, which is strongly desired for display applications. However, high luminance efficiencies for QLEDs with Zn-doped CuInS₂ and AgInS₂ have not been realized yet.

In this study, we investigated the optical and chemical properties of ligand-exchanged ZnCuInS₂ QDs, in which the oleylamine ligands were exchanged with alkyl thiol ligands. We also evaluated QLEDs with ZnCuInS₂ QD layers, and the carbon chain length of the alkyl thiol ligand was varied to investigate the relationship between the device performance and the length of the alkyl thiol ligand.

2. Experimental

A ZnCuInS₂ QD solution in hexane was synthesized by a conventional hot soap method [18], [19]. At first, in-
dium(III) acetate (312 mg, 1.07 mmol), copper(I) chloride (12.9 mg, 0.13 mmol), thiourea (152 mg, 2.0 mmol), zinc acetate dihydrate (146.8 mg, 0.67 mmol), and oleylamine (40 ml) were mixed in a three-necked flask. After heating at 120 °C for 10 min to dissolve the aforementioned raw materials, the flask was heated at 220 °C for 10 min in a nitrogen atmosphere, resulting in the formation of a ZnCuInS₂ core. The synthesized QD solution was precipitated with excess acetone to remove unreacted raw materials. The solution was centrifuged at 20000 rpm for 20 min, and the supernatant was then decanted. The organic ligand of the QD was exchanged from oleylamine to alkyl thiol with a different carbon chain length through the above-mentioned procedure. Here octanethiol (sample A), 1-decanethiol (sample B), dodecanethiol (sample C), and hexadecanethiol (sample D) were used as the organic ligands. These alkyl thiol ligands were respectively injected in the synthesized ZnCuInS₂ solution, and the mixed solutions were heated at 60 °C for 4 h for the ligand-exchange process. Finally, residues were removed by a centrifugation process, and the concentration of the solution was controlled as 10 mg/ml for all the samples by evaporating hexane.

A typical device structure was glass substrate/indium tin oxide (ITO, 150 nm)/ZnO (30 nm)/ZnCuInS₂ QDs/4,4’-bis(N-carbazolyl)-1,1’-biphenyl (CBP, 40 nm)/MoO₃ (10 nm)/Al (100 nm) [19], which is generally known as an inverted structure [20], [21]. At first, a ZnO precursor solution containing zinc acetate dihydrate (precursor, 541 mg), 2-methoxyethanol (solvent, 5.0 ml), and monoethanolamine (stabilizer, 0.01 ml) was spin-coated on the top of an ITO-coated substrate, which was cleaned by ultrasonic wave and ultraviolet ozone treatments just before use. After spin coating the ZnO layer at a rotation speed of 3000 rpm, the sample was annealed at 220 °C for 10 min [22]. A ZnCuInS₂ QD solution was subsequently spin coated at a rotation speed of 2000 rpm for 1 min, and the resulting device was annealed at 130 °C for 10 min. Finally, CBP (40 nm), MoO₃ (10 nm), and Al layers were thermally evaporated on the device in a vacuum chamber.

The PL spectrum was measured using a fluorescence meter (FluoroMax-3, Horiba Jobin Iyon). The Fourier-transform infrared (FT-IR) spectrum was measured using an FT-IR spectrometer (FT/IR-4700, JASCO). The PL-QY was measured using a PL quantum yield measurement system (QEMS-2000, Systems Engineering). The thermal characteristics were measured using a thermogravimetry-differential thermal analyzer (TG/DTA, Hitachi High-Technologies, TG-DTA6200). The surface morphology was evaluated using an atomic force microscope (AFM, Seiko, SPA-300). The current density-voltage, luminance-voltage, and current efficiency-current density characteristics were measured using a DC-voltage current source/monitor (6241A, ADCMT) and a luminance meter (LS-100, Konicaminolta).

3. Results and Discussion

Figure 1 shows the normalized PL spectra of ZnCuInS₂ QD solutions dispersed in hexane, which contained different alkyl thiol ligands such as octanethiol (OT, sample A), 1-decanethiol (DT, sample B), dodecanethiol (DDT, sample C), and hexadecanethiol (HDT, sample D). The excitation wavelength was fixed at 375 nm, and the carbon chain lengths of the alkyl thiol ligands were 8, 10, 12, and 16 for OT, DT, DDT, and HDT, respectively. The PL spectra of all the ZnCuInS₂ QDs with different alkyl thiol ligands showed almost the same peak wavelength at approximately 610 nm, and the full width at half maximum (FWHM) was approximately 130 nm for all the samples. The FWHM of CuInS₂ was much larger than that of CdSe/ZnS QDs (approximately 23–29 nm) [23], [24], and almost the same trend was observed even though Zn was doped in the CuInS₂ QD. This is almost the same value as reported in previous papers [25]. In addition, PL-QYs of samples A, B, C, and D were determined to be 8.5, 11.5, 9.5, and 9.6%, respectively, by exciting ultraviolet light with the wavelength of 375 nm. This result indicates that the carbon chain length of the connected alkyl thiol ligand did not affect the PL-QY of ZnCuInS₂.

We then evaluated the chemical and physical characteristics of the ligand-exchanged ZnCuInS₂ QD using TG/DTA analysis and FT-IR spectroscopy. Figures 2 (a) and 2(b) show the FT-IR spectra of the raw materials used for the ligand-exchange process (i.e., octanethiol, 1-decanethiol, dodecanethiol, and hexadecanethiol) and synthesized ZnCuInS₂ QDs with different alkyl thiol ligands, respectively. These FT-IR spectra showed CH₂ and CH₃ bonds. Peaks at 2995 and 2863 cm⁻¹ originate from the CH₂ bond and those at 2922 and 2851 cm⁻¹ correspond to the CH₃ bond of the alkyl thiol ligand. This result indicates that the peaks from the CH₂ bond increased with increasing
from 2800 to 3000 cm$^{-1}$ evaporated below 300 $^\circ$C. Since all the alkyl thiol ligands used in this study differ from different alkyl thiol ligands. The peaks at 2995 and 2863 cm$^{-1}$ originate from the CH$_3$ bond and those at 2922 and 2851 cm$^{-1}$ correspond to the CH$_2$ bond of the organic ligand.

The FT-IR spectra of (a) alkyl thiol and (b) ZnCuInS$_2$ QDs with different alkyl thiol ligands are shown in Fig. 2. The spectra show that the CH$_3$ bond, which is due to the oleylamine solvent, is present in all cases. The CH$_2$ bond of the organic ligand is also visible in the spectra.

Next, we calculated the CH$_2$/CH$_3$ ratio from the FT-IR spectra shown in Fig. 2. Figure 3 shows the relationship between the carbon chain length of the alkyl thiol ligands and the CH$_2$/CH$_3$ ratio of raw materials and ZnCuInS$_2$ QDs. The CH$_2$/CH$_3$ ratio continuously increased with increasing carbon chain length of the alkyl thiols for both cases. The reason for this is quite simple. One edge of the alkyl thiol contains the CH$_3$ bond, and the rest part contains the CH$_2$ bond. Therefore, the CH$_2$/CH$_3$ ratio corresponds to the carbon chain length of the alkyl thiol ligand as shown in Fig. 3, and the result in Fig. 3 (b) indicates that the oleylamine ligand of ZnCuInS$_2$ QDs was successfully exchanged to the alkyl thiol ligand.

The thermal properties of ZnCuInS$_2$ QDs were measured to investigate the weight ratio of the organic ligand to the ZnCuInS$_2$ QD, and Tg of samples A-D are shown in Fig. 4 (a). Since all the alkyl thiol ligands used in this study evaporated below 300 $^\circ$C, the weight loss at 500 $^\circ$C corresponds to the amount of connected organic ligands around the ZnCuInS$_2$ QD. As clearly shown in the inset of Fig. 4 (a), the weight loss at 500 $^\circ$C decreased with decreasing carbon chain length of the alkyl thiol ligand. The molar ratio of oleylamine to alkyl thiol ligands can be calculated from the
layer in the QLED structure, and therefore, we evaluated the carrier transport layer to the QD emitting layer. The molecular weights of the alkyl thiol ligands; the molecular weights of octanethiol, 1-decanethiol, dodecanethiol, and hexadecanethiol are 146.3, 174.0, 202.4, and 258.5, respectively. As a result, the molar ratio of oleylamine to alkyl thiol ligands was 55:45 for all the samples, which was calculated from the CH2/C total ratio in Fig. 3; this result was caused by the difference in the molecular weights of the alkyl thiol ligands.

Figure 4(b) shows the DTG of ZnCuInS2 QDs with alkyl thiol ligands containing different carbon chain lengths ranging from 8 to 16. The feature at 340 °C in the DTG curve corresponds to the evaporation of oleylamine, which indicates that all the oleylamine ligands could not be exchanged with alkyl thiol ligands. This result is in good agreement with the FT-IR spectrum in Fig. 2(b). In addition, the features at lower temperatures ranging from 220 °C to 280 °C correspond to the evaporation of alkyl thiol ligands, and the evaporation temperature was shifted toward the higher temperature region with increasing carbon chain length of the alkyl thiol ligands.

The surface morphology also affects the carrier injection from the carrier transport layer to the QD emitting layer in the QLED structure, and therefore, we evaluated the surface roughness of the spin coated ZnCuInS2 QD layer. The AFM images of the ZnCuInS2 QD thin films are shown in Fig. 5, and the alkyl thiol ligands used were (a) octanethiol, (b) 1-decanethiol, (c) dodecanethiol, and (d) hexadecanethiol. Aggregated QDs were not observed in the AFM images even when short alkyl thiol ligands were used. The root-mean-square roughnesses were 1.3, 1.2, 1.3, and 1.3 nm for samples A, B, C, and D, respectively. This result indicates that the carbon chain length of the alkyl thiol ligands did not affect the surface roughness of the QD layer, and these values are low enough to realize high luminance performance of thin-film emitting devices.

Figure 6 shows the current density-voltage-luminance characteristics of QLEDs with ZnCuInS2 QDs with different carbon chain lengths of alkyl thiol ligands. The alkyl thiols used were (a) octanethiol, (b) 1-decanethiol, (c) dodecanethiol, and (d) hexadecanethiol.

Figure 7 shows the current efficiency-current density characteristics of QLEDs with ZnCuInS2 QDs with different alkyl thiol ligands. The alkyl thiols used were (a) octanethiol, (b) 1-decanethiol, (c) dodecanethiol, and (d) hexadecanethiol. A higher current density was observed when the alkyl thiol with a short carbon chain length was used for the ligand-exchange process. This result clearly indicates that long alkyl thiol ligands prevent carrier transport in the ZnCuInS2 layer, resulting in a low current density under the applied DC voltage. In addition, the luminance was also improved with decreasing carbon chain length of the alkyl thiol ligands due to efficient carrier transport. The highest luminance of 86 cd/m² was realized when octanethiol was used as the organic ligand.

We then estimated the current efficiencies of the de-
Alkyl thiol ligand with a short carbon chain length was used. Finally, we successfully demonstrated efficiency performance and the carbon chain length of the alkyl thiol ligands, and the highest current density-voltage-luminance characteristics in Fig. 6. The efficiency characteristics, which were evaluated from the current density-voltage-luminance characteristics in Fig. 6. The efficiency was improved with decreasing carbon chain length of the alkyl thiol ligands, and the highest current efficiency of 0.083 cd/A was obtained. This value is quite low compared with reported QLEDs with Cd-free QDs such as InP and CuxS2 [10, 15]. However, this is the first demonstration of QLEDs with ligand-exchanged ZnCuInS2 QDs, and the thick and multiple shell coating layers are useful techniques for realizing highly efficient QLEDs with ZnCuInS2 QDs.

4. Conclusion

In conclusion, we investigated the ligand-exchange process for ZnCuInS2 QDs and the relationship between the luminescence performance and the carbon chain length of the alkyl thiol ligands, which was connected around the ZnCuInS2 QDs. By evaluating the FT-IR spectrum and Tg/DTG, it was found that approximately half of the oleylamine ligands were exchanged to alkyl thiol ligands with different carbon chain lengths. Finally, we successfully demonstrated efficient carrier transport and improved luminescence when the alkyl thiol ligand with a short carbon chain length was used.

References

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